NSN 5962-01-352-1006

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View Online at https://aerobasegroup.com/nsn/5962-01-352-1006
Overall Height:
0.432 inches
Body Length:
1.490 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.172 inches and 0.217 inches
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
5895-01-299-3419 converter, signal data
Features Provided:
Hermetically sealed and burn in and monolithic and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
25 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
55.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
14.0 volts total supply
Capitance Rating Per Characteristic:
12.00 input picofarads and 14.00 output picofarads
Time Rating Per Chacteristic:

Memory Device Type:

120.00 nanoseconds delay

Eprom

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type	And	Quantity:
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28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0